Single Phase Uni-directional Power / Energy Metering IC with Instantaneous Pulse Output

SA2002E



FEATURES

- Functionally compatible with the SA9602E with reduced external components
- Uni-directional power and energy measurement
- Meets the IEC 521/1036 Specification requirements for Class 1 AC Watt hour meters
- Protected against ESD

DESCRIPTION

The SAMES SA2002E is an enhancement of the SA9602E, as the circuit contains the oscillator on chip.

The SAMES SA2002E single phase uni-directional power/energy metering integrated circuit generates a pulse rate output with a frequency proportional to the power consumption.

The SA2002E performs a calculation for active power. The method of calculation takes the power factor into account. Energy consumption can be determined by the power measurement being integrated over time.

- Total power consumption rating below 25mW
- Adaptable to different types of current sensors
- Operates over a wide temperature range
- Precision voltage reference on-chip
- Precision oscillator on-chip

This innovative universal single-phase power/energy metering integrated circuit is ideally suited for energy calculations in applications such as residential municipal metering and factory energy metering and control.

The SA2002E integrated circuit is available in 8, 14 and 20 pin dual-in-line plastic (PDIP) as well as 16 and 20 pin small outline (SOIC) package types.

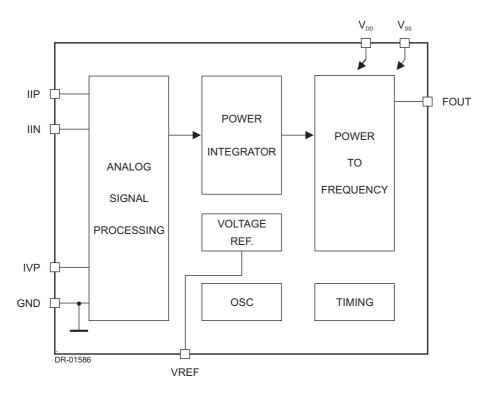


Figure 1: Block diagram



ELECTRICAL CHARACTERISTICS

 $(V_{DD} = 2.5V, V_{SS} = -2.5V)$, over the temperature range -10° C to $+70^{\circ}$ C[#], unless otherwise specified.)

Parameter	Symbol	Min	Тур	Мах	Unit	Condition
Operating temp. Range	T _o	-25		+85	°C	
Supply Voltage: Positive	V _{DD}	2.25		2.75	V	
Supply Voltage: Negative	V _{ss}	-2.75		-2.25	V	
Supply Current: Positive	I _{DD}		3	5	mA	
Supply Current: Negative	I _{ss}		3	5	mA	
Current Sensor Inputs (Diffferential)						
Input Current Range	I ₁₁	-25		+25	μA	Peak value
Voltage Sensor Input (Asymmetrical)						
Input Current Range	I _{IV}	-25		+25	μA	Peak value
Pin FOUT Output High Voltage Output Low Voltage	V _{ol} V _{oh}	V _{DD} -1		V _{ss} +1	V V	
Pulse Rate FOUT	f_p		1160		Hz	At rated input conditions
Pin VREF Ref. Current Ref. Voltage	-I _R V _R	45 1.1	50	55 1.3	μA V	With R = $24k\Omega$ connected to V _{ss} Reference to V _{ss}

Extended Operating Temperature Range available on request.

ABSOLUTE MAXIMUM RATINGS*

Parameter	Symbol	Min	Мах	Unit
Supply Voltage	V_{DD} - V_{SS}	-0.3	6.0	V
Current on any pin	I _{PI N}	-150	+150	mA
Storage Temperature	T _{stg}	-40	+125	°C
Operating Temperature	T _o	-25	+85	°C

*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these or any other condition above those indicated in the operational sections of this specification, is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability.

sames

SA2002E

PIN DESCRIPTION

8 Pin	14 Pin	16 Pin	20 Pin	Designation	Description
8	14	16	20	GND	Analog Ground. The voltage to this pin should be mid-way between $V_{_{\rm DD}}$ and $V_{_{\rm SS}}.$
4	5	5	8	V_{dd}	Positive supply voltage. The voltage to this pin is typically +2.5V if a shunt resistor is used for current sensing or in the case of a current transformer a +5V supply can be applied.
6	10	12	14	V _{ss}	Negative supply voltage. The voltage to this pin is typically -2.5V if a shunt resistor is used for current sensing or in the case of a current transformer a 0V supply can be applied.
7	13	15	19	IVP	Analog Input for Voltage. The current into the A/D converter should be set at $14\mu A_{RM}$ at nominal mains voltage. The voltage sense input saturates at an input current of ±25µA peak.
1, 2	1, 2	1, 2	1, 2	IIN, IIP	Inputs for current sensor. The shunt resistor voltage from each channel is converted to a current of $16\mu A_{\rm RM}$ sat rated conditions. The current sense input saturates at an input current of $\pm 25\mu A$ peak.
3	3	3	3	VREF	This pin provides the connection for the reference current setting resistor. A $24k\Omega$ resistor connected to V _{ss} set the optimum operating condition.
5	8	6	12	FOUT	Pulse rate output. Refer to pulse output format for a description of the pulse rate.
	4	4	4	TP1	Leave pins unconnected.
	6	7	5	TP2	
	7	8	6	TP3	
	9	9	7	TP4	
	11	10	9	TP5	
	12	11	10	TP6	
		13	11	TP7	
		14	13	TP8	
			15	TP9	
			16	TP10	
			17	TP11	
			18	TP12	



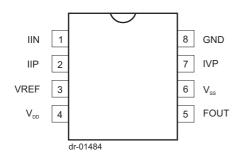


Figure 2: Pin connections: Package: PDIP8

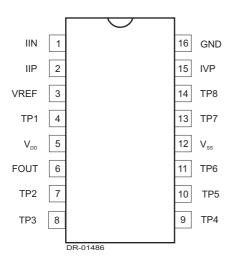


Figure 4: Pin connections: Package: SOIC16

ORDERING INFORMATION

Part Number	Package
SA2002EPA	PDIP8
SA2002EPA	PDIP14
SA2002EPA	PDIP20
SA2002ESA	SOIC16
SA2002ESA	SOIC20

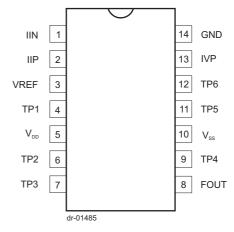


Figure 3: Pin connections: Package: PDIP14

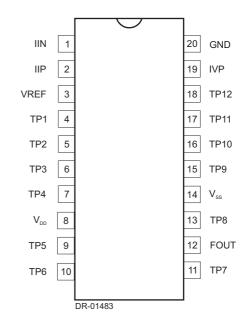


Figure 5: Pin connections: Package: PDIP20, SOIC20

FUNCTIONAL DESCRIPTION

The SA2002E is a CMOS mixed signal Analog/Digital integrated circuit, which performs power/energy calculations across a power range of 1000:1, to an overall accuracy of better than Class 1.

The integrated circuit includes all the required functions for 1phase power and energy measurement such as two oversampling A/D converters for the voltage and current sense inputs, power calculation and energy integration. Internal offsets are eliminated through the use of cancellation procedures. The SA2002E generates pulses, the frequency of which is proportional to the measured power consumption. One frequency output (FOUT) is available. The pulse rate follows the instantaneous power consumption measured.

POWER CALCULATION

In the application circuit (figure 6), the voltage drop across the shunt will be between 0 and $16mV_{\mbox{\tiny RMS}}$ (0 to 80A through a shunt resistor of $200\mu\Omega$) The voltage is converted to a current of between 0 and $16uA_{\mbox{\tiny RMS}}$, by means of resistors R1 and R2. The current sense inputs saturates at an input current of $\pm 25\mu A$ peak.

sames

For the voltage sensor input, the mains voltage (230VAC) is divided down through a divider (R3, R4 and P1) to $14V_{\text{RMS}}$. The current into the A/D converter input is set at $14\mu A_{\text{RMS}}$ at nominal mains voltage, via resistor R5 (1M Ω). P1 may be varied for calibration purposes.

In this configuration, with a mains voltage of 230V and a current of 80A, the output frequency measured on the FOUT pin is 1160Hz. In this case one pulse on FOUT correspond to an energy consumption of 18.4kW/1160Hz = 15.86Ws.

ANALOG INPUT CONFIGURATION

The input circuitry of the current and voltage sensor inputs is illustrated in figure 7. These inputs are protected against electrostatic discharge through clamping diodes. The feedback loops from the outputs of the amplifiers A_1 and A_v generate virtual shorts on the signal inputs. Exact duplications of the input currents are generated for the analog signal processing circuitry.

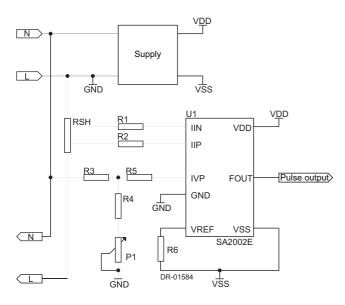


Figure 6: Application circuit

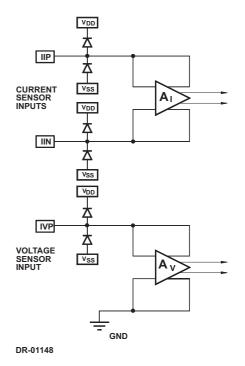


Figure 7: Internal analog input configuration



ELECTROSTATIC DISCHARGE (ESD) PROTECTION

The SA2002E integrated circuit's inputs/outputs are protected against ESD.

POWER CONSUMPTION

The power consumption rating of the SA2002E integrated circuit is less than 25 mW.

INPUT SIGNALS VREF

A bias resistor of $24k\Omega$ set optimum bias conditions on chip. Calibration of the SA2002E should be done on the voltage input as described in Typical Applications.

Current sense input (IIP and IIN)

Figure 6 shows the typical connections for the current sensor input. The resistor R1 and R2 define the current level into the current sense inputs of the SA2002E. At maximum rated current the resistor values should be selected for input currents of $16 \mu A_{\text{RMS}}$.

Values for resistors R1 and R2 can be calculated as follows:

 $R1 = R2 = (I_{L}/16\mu A) \times RSH/2$

Where I_{L} = Line current

RSH = Shunt resistor or termination resistor if a CT is used as the current sensor.

The value of RSH, if used as the CT's termination resistor, should be less than the DC resistance of the CT's secondary winding. The voltage drop across RSH should not be less than $16mV_{\text{RMS}}$ at rated currents.

Voltage Sense Input (IVP)

The current into the A/D converter should be set at $14\mu A_{\text{RMS}}$ at nominal mains voltage. The voltage sense input saturates at an input current of $\pm 25\mu A$ peak. Referring to figure 6 the typical connections for the voltage sense input is illustrated. Resistors R3, R4 and R5 set the current for the voltage sense input. The mains voltage is divided down to $14V_{\text{RMS}}$. The current into the A/D converter input is set at $14\mu A_{\text{RMS}}$ via resistor R5.

OUTPUT SIGNAL Pulse output (FOUT)

The output on FOUT is a pulse density signal representing the instantaneous power/energy measurement as shown in figure 8. The minimum timing characteristics are shown in the figure 9. The output frequency may be calculated using the following formula:

 $f = 11.16 \text{ x FOUT x} (I_1 \text{ x } I_2) / I_R^2$

Where:

FOUT = Typical rated output frequency (1160Hz)

 $I_{_{\rm I}}$ = Input current on current sense input (16 μA at rated conditions)

 $I_{\rm v}$ = Input current on voltage sense input (16µA at rated conditions)

 $I_{_{\rm R}}$ = Reference current on VREF typically 50 μA

An integrated anti-creep function does not allow output pulses on FOUT if no power is measured by the device.

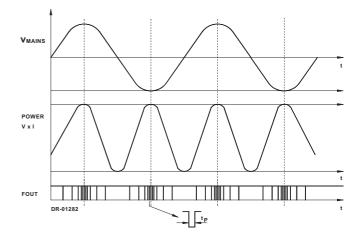


Figure 8: FOUT instantaneous pulse output

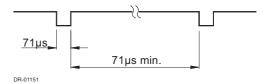


Figure 9: FOUT pulse width

TYPICAL APPLICATION

In figure 10, the components required for stand alone power metering application, is shown. The application uses a shunt resistor for the mains current sensing. The meter is designed for 220V/40A I_{MAX} operation. The most important external components for the SA2002E integrated circuit are the current sense resistors, the voltage sense resistors as well as the bias setting resistor.

BIAS RESISTOR

R13 defines all on-chip and reference currents. With R13=24k Ω , optimum conditions are set. Device calibration is done on the voltage input of the device.

SHUNT RESISTOR

The voltage drop across the shunt resistor at rated current should be at least 20mV. A shunt resistor with a value of $625\mu\Omega$ is chosen. The voltage drop across the shunt resistor is 25mV at rated conditions (Imax). The power dissipation in the current sensor is:

 $P=(40A)^2 \times 625 \mu\Omega = 1W.$

CURRENT SENSE RESISTORS

The resistors R6 and R7 define the current level into the current sense inputs of the device. The resistor values are selected for an input current of 16μ A on the current inputs of the SA2002E at rated conditions. According to equation described in the Current Sense inputs section:

R6 = R7 = (I_L/16μA)xRSH/2 = 40A/16μAx625μΩ/2 = 781.2Ω

A resistor with value of 820Ω is chosen, the 5% deviation from the calculated value will be compensated for when calculating resistor values for the voltage path.

VOLTAGE DIVIDER

The voltage divider is calculated for a voltage drop of 14V + 5%(14.7V). Equations for the voltage divider in figure 9 are:

RA = R1 + R2 + R3 RB = R12 || (R11+P1)

Combining the two equations gives: (RA + RB)/220V = RB/14.7V

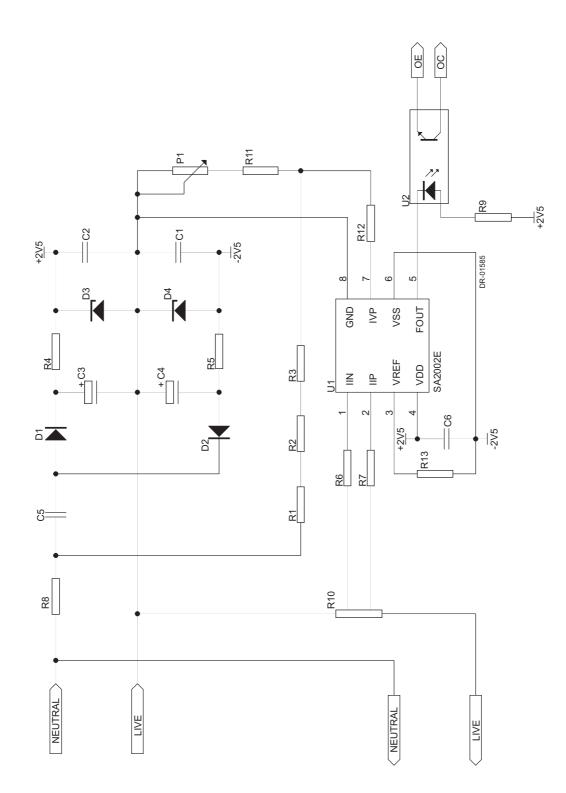
A 5k trimpot will be used in the voltage channel for meter calibration. The center position on the pot is used in the calculations. P1 = $2.5k\Omega$ and values for resistors R11 = $22k\Omega$ and R12 = $1M\Omega$ is chosen.

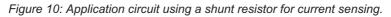
Substituting the values will result in:

RB = $23.91k\Omega$ RA = RB x (230V/14.7V - 1) = $333k\Omega$ so the resistor values of R1, R2 and R3 are chosen to be $110k\Omega$.









8/10



Parts List for Application Circuit: Figure 10

Symbol	Description	Detail		
U1	SA2002E	PDIP8		
D1	Diode, Silicon, 1N4002			
D2	Diode, Silicon, 1N4002			
D3	Diode, Zener, 2.4V			
D4	Diode, Zener, 2.4V			
R1	Resistor, 110k, 1/4W, 1% metal			
R2	Resistor, 110k, 1/4W, 1% metal			
R3	Resistor, 110k, 1/4W, 1%, metal			
R4	Resistor, 680, 1/4W, 1%, metal			
R5	Resistor, 680, 1/4W, 1%, metal			
R6	Resistor, 820, 1/4W, 1%, metal	Note 1		
R7	Resistor, 820, 1/4W, 1%, metal	Note 1		
R8	Resistor, 47R, 2W, 5%, wire wound			
R9	Resistor, 680, 1/4W, 5%, carbon			
R10	Shunt resistor			
R11	Resistor, 22k 1/4W, 1%, metal			
R12	Resistor, 1M, 1/4W, 1%, metal			
R13	Resistor, 24k, 1/4W, 1%, metal			
P1	Trim pot, 5k, Multi turn			
C1	Capacitor, 220nF			
C2	Capacitor, 220nF			
C3	Capacitor, 100uF, 16V, electrolytic			
C4	Capacitor, 100uF, 16V, electrolytic			
C5	Capacitor, 330nF, 250VAC			
C6	Capacitor, 820nF	Note 2		
U2	4N35, Opto Coupler			

Note 1: Resistor (R6 and R7) values are dependent on the selected shunt resistor (R14) value. Note 2: Capacitor C6 to be positioned as close as possible to supply pins.



DISCLAIMER:

The information contained in this document is confidential and proprietary to South African Micro-Electronic Systems (Pty) Ltd ("SAMES") and may not be copied or disclosed to a third party, in whole or in part, without the express written consent of SAMES. The information contained herein is current as of the date of publication; however, delivery of this document shall not under any circumstances create any implication that the information contained herein is correct as of any time subsequent to such date. SAMES does not undertake to inform any recipient of this document of any changes in the information contained herein, and SAMES expressly reserves the right to make changes in such information, without notification, even if such changes would render information contained herein inaccurate or incomplete. SAMES makes no representation or warranty that any circuit designed by reference to the information contained herein, will function without errors and as intended by the designer.

Any sales or technical questions may be posted to our e-mail address below: energy@sames.co.za

For the latest updates on datasheets, please visit our web site: http://www.sames.co.za.

SOUTH AFRICAN MICRO-ELECTRONIC SYSTEMS (PTY) LTD

Tel: (012) 333-6021 Tel: Int +27 12 333-6021 Fax: (012) 333-8071 Fax: Int +27 12 333-8071

P O BOX 15888 33 ELAND STREET LYNN EAST 0039 REPUBLIC OF SOUTH AFRICA 33 ELAND STREET KOEDOESPOORT INDUSTRIAL AREA PRETORIA REPUBLIC OF SOUTH AFRICA